NSN 5961-00-481-8506

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-481-8506 **Inclosure Material:** Glass **Overall Length:** 1.000 inches **Terminal Length:** 0.600 inches **Overall Height:** 0.400 inches **Overall Width:** 0.630 inches **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 100.0 reverse voltage, peak all semiconductor device diode **Current Rating Per Characteristic:** 1.00 amperes average forward current averaged over a full 60-hz cycle all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0